

General Description

The AH9281/82 is a one-chip solution for driving two-coil brushless DC motors and fans.

Based on the advanced CDMOS process, the IC contains a Hall-effect sensor, dynamic offset correction and powerful output drivers with 1200mA peak output current capability.

Specially designed for driving large fans, the device is optimized for low start-up voltage. Frequency Generator or Rotation Detection is available. The open drain output makes easier the connectivity with any external interface such as hardware monitoring or Super I/O IC.

The AH9281/82 is available in TO-95 and SOT-89-5 packages.

Features

- High Sensitivity Integrated Hall Sensor
- Low Start-up Voltage
- 5V and 12V Operation
- Peak Output Current up to 1200mA
- Power Efficient CMOS and Power MOSFETs
- Built-in Output Protection Clamping Diode
- Locked Rotor Shutdown and Auto-restart
- Integrated Tachometer (AH9281) or Alarm (AH9282) Signal Output
- ESD Rating: 6000V (Human Body Model) 400V (Machine Model)

Applications

- 5V/12V DC Brushless Motor/Fan
- PC, Server, Laptop Cooling Fan
- Power Supply Cooling Fan
- Large or Small Fans



Figure 1. Package Types of AH9281/82



Pin Configuration



Figure 2. Pin Configuration of AH9281/82

Pin Description

Pin Number		Pin Name	Function			
TO-95	SOT-89-5		Function			
1	1	VCC	Power supply pin			
2	3	FG/RD	Frequency Generator (Rotation Detection) open drain output			
3	4	DO	Output pin 1			
4	5	DOB	Output pin 2			
5	2	GND	Ground pin			



Functional Block Diagram



A (B) A for TO-95 B for SOT-89-5

Figure 3. Functional Block Diagram of AH9281/82



Ordering Information



Package	Temperature Range	Output Signal	Part Number Marking ID		Packing Type
TO 05		FG	AH9281Z5-G1	9281Z5-G1	Bulk
10-95	-40 to 125°C	RD	AH9282Z5-G1	9282Z5-G1	Bulk
SOT-89-5		FG	AH9281RTR-G1	G41C	Tape & Reel
		RD	AH9282RTR-G1	G41D	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.



Absolute Maximum Ratings (Note 1, T_A=25°C)

Parameter	Symbol	Value		Unit	
Supply Voltage	V _{CC}	18		V	
Supply Current (Fault)	I _{CC}	6		mA	
Peak Output Current	I _{OUT_P}	1200		mA	
Continuous Output Current	I _{OUT_C}	600		mA	
FG/RD Pull-up Voltage	V_{FG}/V_{RD}	28		V	
Deres Dissingtion	P	TO-95	600	mV	
Power Dissipation	PD	SOT-89-5	800		
Thermal Resistance	A.	TO-95	208	°C/W	
(Junction to Ambient)	OJA	SOT-89-5	156	C/ W	
Storage Temperature	T _{STG}	-55 to 150		°C	
ESD (Human Body Model)	ESD	6000		V	
ESD (Machine Model)	ESD	400		V	

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V _{CC}	2.5	16	V
Operating Ambient Temperature	T _A	-40	125	°C



Electrical Characteristics

 $V_{CC}=12V$, $T_A=25^{\circ}C$, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Supply Voltage	V _{CC}	Operating	2.5	12	16	V
Supply Current	I _{CC}	Average		4	6	mA
Output Current	I _{OUT}				500	mA
Output Leakage Current	I _{LEAKAGE}			0.1	10	μΑ
Saturation Voltage	V _{SAT}	I _{OUT} =350mA		600	1000	mV
Output ON Time	t _{ON}			0.8		S
Output OFF Time	t _{OFF}			5		S
FG/RD Output Low Voltage	V_{FGL}/V_{RDL}	I _{FG} =5mA		0.1	0.2	V
FG/RD Output Leakage Current	I _{FGLK} /I _{RDLK}	V_{FG}/V_{RD} =12V		0.1	10	μΑ
FG/RD Output Current Limit	I_{FGLIM}/I_{RDLIM}	$V_{FG}/V_{RD}=12V$		30		mA
Output Zener Break-down Voltage	Vz			35		V

Magnetic Characteristics

 V_{CC} =12V, T_A =25°C, unless otherwise specified.

Parameter	Symbol	Min	Тур	Max	Unit
Operating Point	B _{OP}	0	20	50	Gauss
Releasing Point	B _{RP}	-50	-20	0	Gauss
Hysteresis	B _{HYS}		40		Gauss



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BCD Semiconductor Manufacturing Limited



Test Circuit



Figure 4. Basic Test Circuit of AH9281/82



Figure 5. V_{DO} vs. Magnetic Flux Density

Figure 6. V_{DOB} vs. Magnetic Flux Density



Typical Performance Characteristics





Figure 7. Supply Current vs. Supply Voltage

Figure 8. Supply Current vs. Ambient Temperature



Figure 9. $B_{OP}/B_{RP}/B_{HYS}$ vs. Supply Voltage



Figure 10. B_{OP}/B_{RP}/B_{HYS} vs. Ambient Temperature



Typical Performance Characteristics (Continued)





Figure 11. Saturation Voltage vs. Ambient Temperature

Figure 12. Saturation Voltage vs. Output Current



Figure 13. Power Dissipation vs. Ambient Temperature Fig



Figure 14. Power Dissipation vs. Ambient Temperature



Typical Application



Figure 15. Typical Application 1 of AH9281/82 (TO-95, Note 2)

Note 2:

1. D1 is an ordinary diode used to filter the noise from VCC and protect IC if VCC and GND are plugged reversed.

2. R1=47
$$\Omega$$
 typical.

3. $C1=C2=C3=2.2\mu F$ typical, electrolytic capacitors are better. They should be fine tuned based on system design.

4. R2=R3=4.7 Ω typical. They can be cancelled according to system requirement.



Typical Application (Continued)



Figure 16. Typical Application 2 of AH9281/82 (TO-95, Note 3)

Note 3:

1. D1 is an ordinary diode used to filter the noise from VCC and protect IC if VCC and GND are plugged reversed.

2. R1=47 Ω typical.

3. C1 =2.2µF typical, electrolytic capacitors are better. They should be fine tuned based on system design.

4. ZD1 and ZD2 breakdown voltage are 35V.



Typical Application (Continued)



Figure 17. Typical Application 3 of AH9281/82 (SOT-89-5, Note 4)

Note 4:

1. D1 is an ordinary diode used to filter the noise from VCC and protect IC if VCC and GND are plugged reversed.

2. R1=47 Ω typical.

3. $C1=C2=C3=2.2\mu F$ typical, electrolytic capacitors are better. They should be fine tuned based on system design.

4. R2=R3=4.7 Ω typical. They can be cancelled according to system requirement.



Typical Application (Continued)



Figure 18. Typical Application 4 of AH9281/82 (SOT-89-5, Note 5)

Note 5:

1. D1 is an ordinary diode used to filter the noise from VCC and protect IC if VCC and GND are plugged reversed.

2. R1=47 Ω typical.

3. C1=2.2µF typical, electrolytic capacitors are better. They should be fine tuned based on system design.

4. ZD1 and ZD2 breakdown voltage are 35V.



Mechanical Dimensions





Mechanical Dimensions (Continued)

SOT-89-5

Unit: mm(inch)



单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))